



60V Dual P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

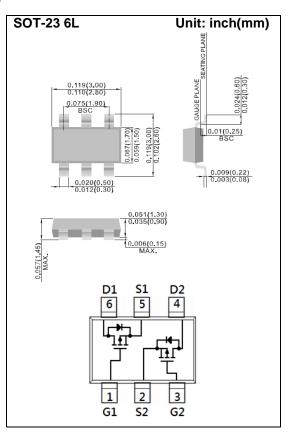
-300mA

Features

- R_{DS(ON)}, V_{GS}@-10V, I_D@-500mA<4Ω
- R_{DS(ON)}, V_{GS}@-4.5V, I_D@-200mA<6Ω
- R_{DS(ON)}, V_{GS}@-2.5V, I_D@-50mA<13Ω
- Advanced Trench Process Technology
- Specially Designed for Relay driver, Speed line drive, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.0141 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-60	V
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V
Continuous Drain Current		I _D	-300	mA
Pulsed Drain Current (Note 4)		I _{DM}	-1000	mA
Power Dissipation	T _a =25°C	P _D	500	mW
	Derate above 25°C		4	mW/°C
Operating Junction and Storage Temperature Range		T_{J} , T_{STG}	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	250	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-1	-1.5	-2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-500mA	-	2.4	4	Ω
		V _{GS} =-4.5V, I _D =-200mA	-	2.65	6	
		V_{GS} =-2.5V, I_{D} =-50mA	-	4.5	13	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-48V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	V _{DS} =-25V, I _D =-100mA, V _{GS} =-4.5V	-	1.1	-	nC
Gate-Source Charge	Q_gs		-	0.3	-	
Gate-Drain Charge	Q_gd		-	0.2	-	
Input Capacitance	Ciss	V _{DS} =-25V, V _{GS} =0V,	-	51	-	pF
Output Capacitance	Coss		-	15	-	
Reverse Transfer Capacitance	Crss	f=1MHZ	-	2.2	-	
Turn-On Delay Time	td _(on)	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	-	4.8	-	
Turn-On Rise Time	tr	V_{DD} =-25V, I_{D} =-100mA, V_{GS} =-10V, R_{G} =6 Ω (Note 1,2)	-	19	-	ns
Turn-Off Delay Time	td _(off)		-	52	-	
Turn-Off Fall Time	tf	NG=077	-	32	-	
Drain-Source Diode						
Maximum Continuous Drain-Source		s	-	-	-300	mA
Diode Forward Current	IS					
Diode Forward Voltage	V_{SD}	I _S =-500mA, V _{GS} =0V	-	-0.95	-1.3	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

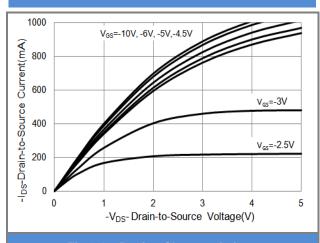


Fig.1 On-Region Characteristics

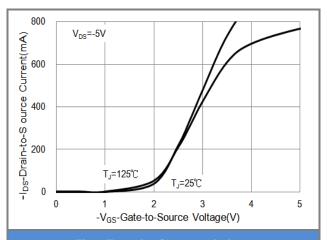


Fig.2 Transfer Characteristics

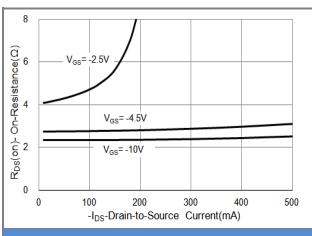


Fig.3 On-Resistance vs. Drain Current

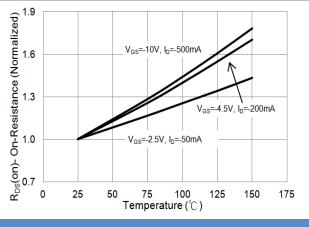
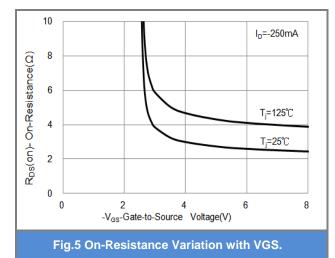
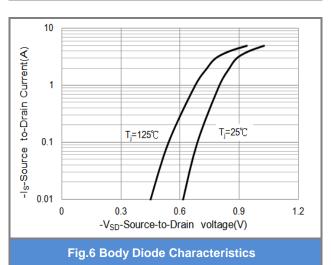


Fig.4 On-Resistance vs. Junction temperature





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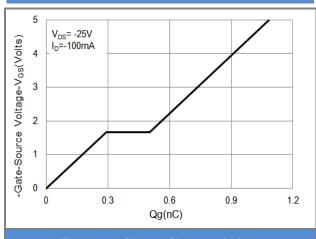


Fig.7 Gate-Charge Characteristics

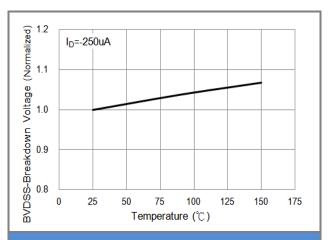


Fig.8 Breakdown Voltage Variation vs. Temperature

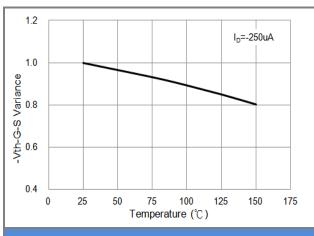


Fig.9 Threshold Voltage Variation with Temperature

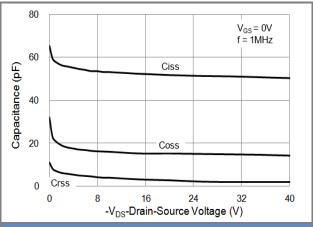


Fig.10 Capacitance vs. Drain-Source Voltage

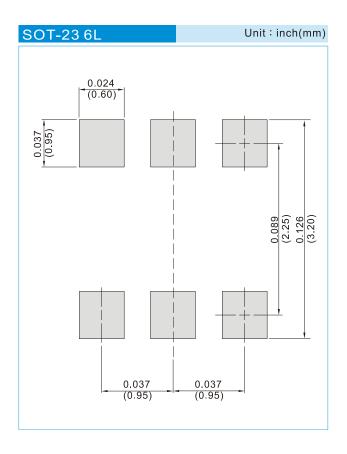




PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJS6839_S1_00001	SOT-23 6L	3K pcs / 7" reel	SG9	Halogen free

MOUNTING PAD LAYOUT







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